

44 GHz Hybrid HEMT Power Amplifiers

D.W. Ferguson, P.M. Smith, P.C. Chao, L.F. Lester, R.P. Smith, P. Ho, A. Jabra and J.M. Ballingall. "44 GHz Hybrid HEMT Power Amplifiers." 1989 MTT-S International Microwave Symposium Digest 89.3 (1989 Vol. III [MWSYM]): 987-990.

Doped Channel 0.25 μ m gate length InGaAs Pseudomorphic HEMTs developed in our laboratory have exhibited state-of-the-art power performance at millimeter wave frequencies, including output power density of 0.93 W/mm and power added efficiency of 41% at 44 GHz. Using these devices, two Q-Band hybrid power amplifiers have been developed. A two-stage design has produced 108 mW output power gain with 9.5dB and 26.5% power added efficiency. A three-stage design produced 251 mW output power with 13.6dB of gain and 26.8% power added efficiency. The peak efficiency of the three stage amplifier was 31.3% when biased differently. The linear gain of these amplifiers was 12 and 20 dB respectively, These results clearly show the potential of these devices for millimeter wave transmitters.

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